

# NPN General Purpose Transistor MMBT2222AM3T5G

The MMBT2222AM3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

#### **Features**

- Reduces Board Space
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	$V_{CEO}$	40	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	75	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current - Continuous	Ic	600	mAdc

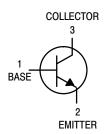
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	265 2.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



### MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



AA

= Specific Device Code

1 = Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT2222AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel
NSVMMBT2222AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		1		I	
Collector - Emitter Breakdown Voltage (I <sub>C</sub> =	10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	40	_	Vdc
Collector – Base Breakdown Voltage (I <sub>C</sub> = 10	V <sub>(BR)CBO</sub>	75	-	Vdc	
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 10 μ	V <sub>(BR)EBO</sub>	6.0	-	Vdc	
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB</sub>	<sub>((off)</sub> = 3.0 Vdc)	I <sub>CEX</sub>	-	10	nAdc
Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 60 \text{ Vdc}, I_E = 0, T_A = 125^{\circ}\text{C})$	;)	I <sub>CBO</sub>	- -	0.01 10	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0	0)	I <sub>EBO</sub>	-	100	nAdc
Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub>	= 3.0 Vdc)	I <sub>BL</sub>	-	20	nAdc
ON CHARACTERISTICS					
$\label{eq:DC Current Gain} \begin{array}{l} \text{(I}_{C} = 0.1 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 1.0 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc, T}_{A} \\ \text{(I}_{C} = 150 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 150 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 150 \text{ mAdc, V}_{CE} = 1.0 \text{ Vdc)} \\ \text{(I}_{C} = 500 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 500 \text{ mAdc, V}_{CE} = 10 \text{ Vdc)} \\ \text{(I}_{C} = 10 \text{ Vdc)} \\ \text{(I}_$	lote 3) Note 3)	h <sub>FE</sub>	35 50 75 35 100 50 40	- - - 300 - -	ı
Collector – Emitter Saturation Voltage (Note ( $I_C$ = 150 mAdc, $I_B$ = 15 mAdc) ( $I_C$ = 500 mAdc, $I_B$ = 50 mAdc)	V <sub>CE(sat)</sub>	- -	0.3 1.0	Vdc	
Base – Emitter Saturation Voltage (Note 3) $(I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc})$ $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$	V <sub>BE(sat)</sub>	0.6 -	1.2 2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (Note 4 ( $I_C$ = 20 mAdc, $V_{CE}$ = 20 Vdc, f =		f <sub>T</sub>	300	-	MHz
Output Capacitance ( $V_{CB}$ = 10 Vdc, $I_{E}$ = 0, f	= 1.0 MHz)	C <sub>obo</sub>	-	8.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_{C} = 0$ , f	= 1.0 MHz)	C <sub>ibo</sub>	-	25	pF
Input Impedance $ \begin{aligned} \text{(I}_{C} = \text{1.0 mAdc, V}_{CE} = \text{10 Vdc, f} = \\ \text{(I}_{C} = \text{10 mAdc, V}_{CE} = \text{10 Vdc, f} = \end{aligned} $		h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio $ \begin{array}{l} \text{(I}_{C} = 1.0 \text{ mAdc, V}_{CE} = 10 \text{ Vdc, f} = 1.0 \text{ kHz)} \\ \text{(I}_{C} = 10 \text{ mAdc, V}_{CE} = 10 \text{ Vdc, f} = 1.0 \text{ kHz)} \end{array} $		h <sub>re</sub>	- -	8.0 4.0	X 10 <sup>-4</sup>
Small – Signal Current Gain ( $I_C$ = 1.0 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz) ( $I_C$ = 10 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	50 75	300 375	-
Output Admittance		h <sub>oe</sub>	5.0 25	35 200	μmhos
Collector Base Time Constant ( $I_E = 20 \text{ mAdc}, V_{CB} = 20 \text{ Vdc}, f = 31.8 \text{ MHz}$ )		rb, C <sub>c</sub>	_	150	ps
Noise Figure (I <sub>C</sub> = 100 $\mu$ Adc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)		NF	-	4.0	dB
SWITCHING CHARACTERISTICS					
Delay Time	(V <sub>CC</sub> = 30 Vdc, V <sub>BE(off)</sub> = -0.5 Vdc,	t <sub>d</sub>	-	10	
Rise Time	I <sub>C</sub> = 150 mAdc, I <sub>B1</sub> = 15 mAdc)	t <sub>r</sub>	-	25	ns
Storage Time	(V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 150 mAdc,	ts	-	225	ne
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$	t <sub>f</sub>	-	60	- ns

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
 f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

### **SWITCHING TIME EQUIVALENT TEST CIRCUITS**

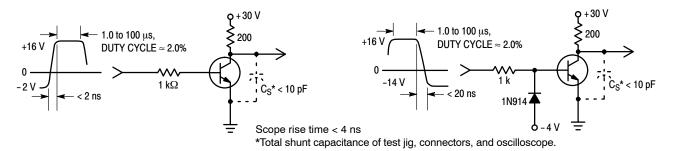


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

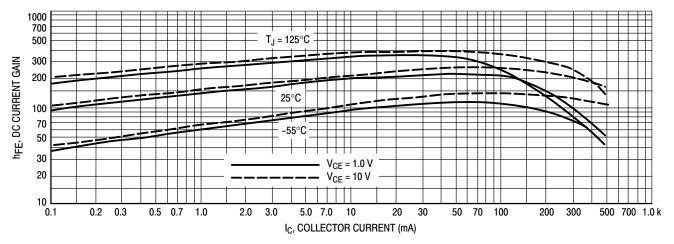


Figure 3. DC Current Gain

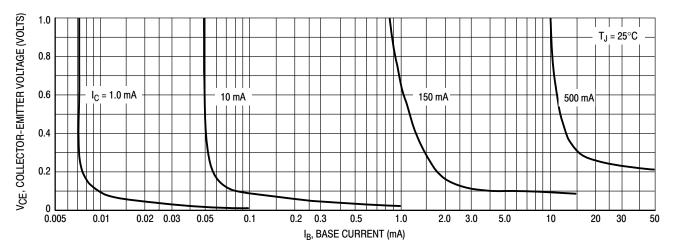


Figure 4. Collector Saturation Region

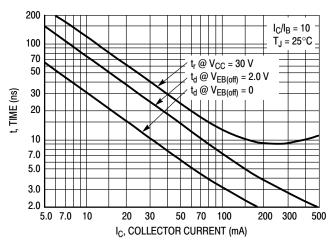


Figure 5. Turn - On Time

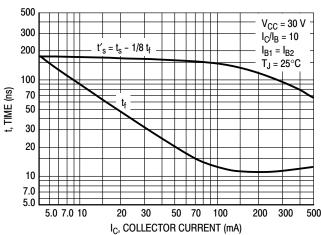


Figure 6. Turn-Off Time

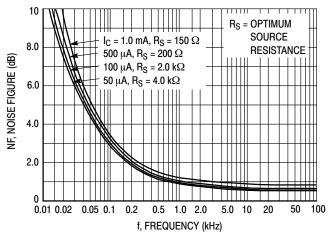


Figure 7. Frequency Effects

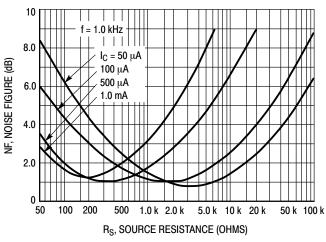


Figure 8. Source Resistance Effects

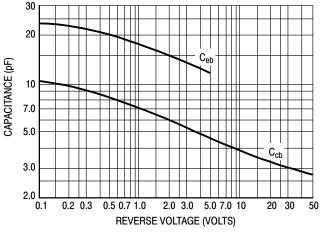


Figure 9. Capacitances

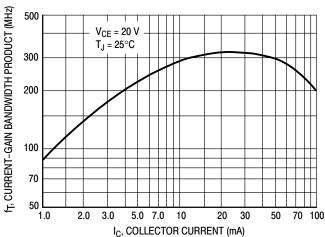


Figure 10. Current-Gain Bandwidth Product

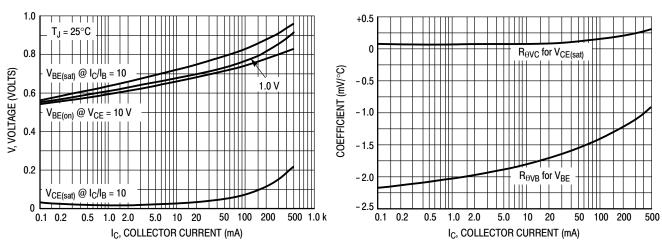


Figure 11. "On" Voltages

Figure 12. Temperature Coefficients





#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

**DATE 24 JAN 2024** 

MAX.

0.55

0.27

0.37

0.17

1.25

0.85

1.25

0.25

MILLIMETERS

 $N\square M$ .

0.50

0.21

0.31

0.12

1.20

0.80

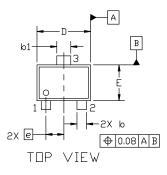
0.40 BSC

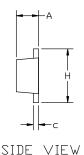
1.20

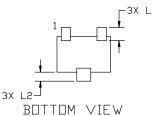
0.29 REF

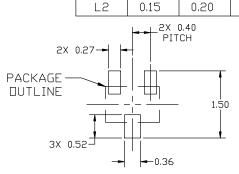
#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH, MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.









DIM

Α

b

b1

c D

Ε

e H

L

MIN.

0.45

0.15

0.25

0.07

1.15

0.75

1.15

# RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

# GENERIC MARKING DIAGRAM\*



XX = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. GATE
2. EMITTER	2. N/C	2. ANODE	<ol><li>CATHODE</li></ol>	<ol><li>SOURCE</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>ANODE</li></ol>	<ol><li>DRAIN</li></ol>

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DESCRIPTION:	SOT-723 1.20x0.80x0.50, 0.40P		PAGE 1 OF 1

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